

HAT2197R

Silicon N Channel Power MOS FET Power Switching

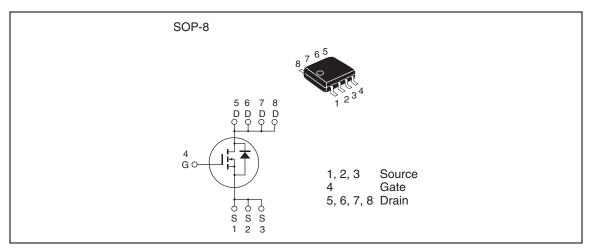
REJ03G0061-0201Z Rev.2.01 Nov.30.2016

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS(on)} = 5.3 \text{ m}\Omega \text{ typ.}$ (at $V_{GS} = 10 \text{ V}$)

Outline





Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	16	А
Drain peak current	Note1 I _{D(pulse)}	128	А
Body-drain diode reverse drain current	I _{DR}	16	А
Avalanche current	I _{AP} Note 2	16	А
Avalanche energy	EAR Note 2	25.6	mJ
Channel dissipation	Pch Note3	2.5	W
Channel to ambient thermal impedance	θch-a ^{Note3}	50	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

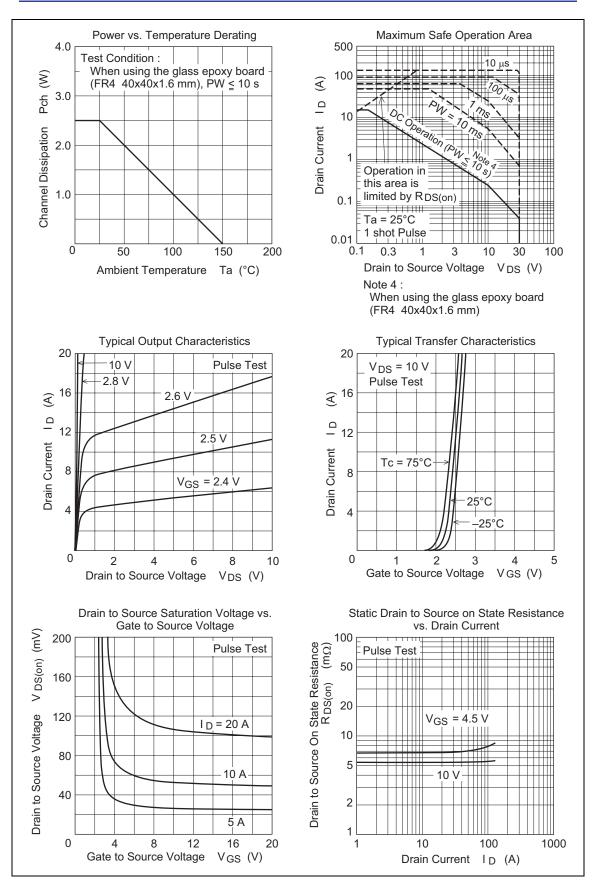
3. When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW \leq 10s

Electrical Characteristics

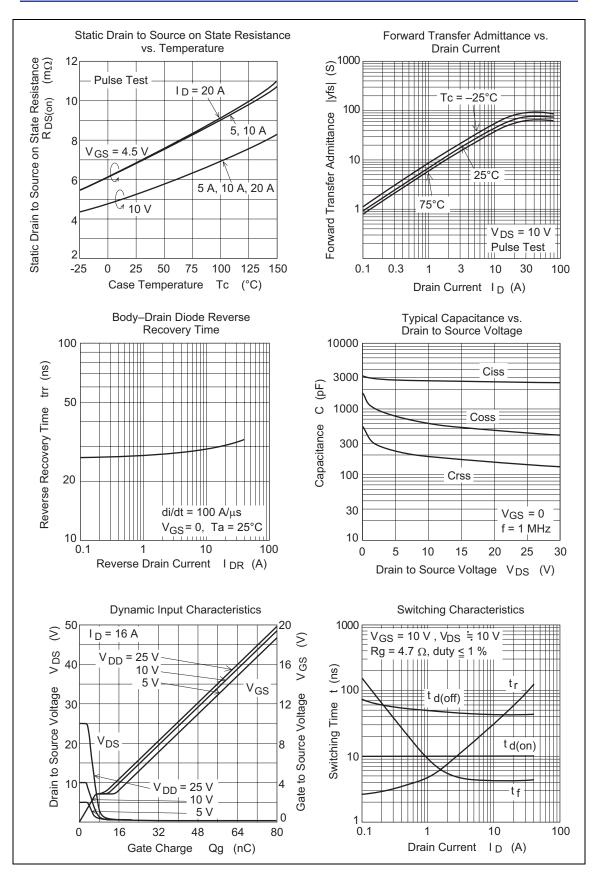
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	I _D = 10 mA, V _{GS} = 0
Gate to source leak current	I _{GSS}	_	_	± 0.1	μA	V_{GS} = ±20 V, V_{DS} = 0
Zero gate voltage drain current	I _{DSS}	—	_	1	μA	$V_{DS} = 30 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.0	_	2.5	V	V_{DS} = 10 V, I _D = 1 mA
Static drain to source on state	R _{DS(on)}	_	5.3	6.7	mΩ	I_D = 8 A, V_{GS} = 10 V ^{Note4}
resistance	R _{DS(on)}	_	6.8	9.9	mΩ	I_D = 8 A, V_{GS} = 4.5 V ^{Note4}
Forward transfer admittance	y _{fs}	22	38	_	S	I_D = 8 A, V_{DS} = 10 V ^{Note4}
Input capacitance	Ciss	_	2650		pF	V _{DS} = 10 V
Output capacitance	Coss	_	610		pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	190		pF	f = 1 MHz
Gate Resistance	Rg	_	1.2	_	Ω	
Total gate charge	Qg	_	18	_	nC	V _{DD} = 10 V
Gate to source charge	Qgs	_	7.5	_	nC	V _{GS} = 4.5 V
Gate to drain charge	Qgd	_	4.2	_	nC	I _D = 16 A
Turn-on delay time	t _{d(on)}	_	10	_	ns	V _{GS} = 10 V, I _D = 8 A
Rise time	tr	_	25	_	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	t _{d(off)}	_	45	_	ns	 R _L = 1.25 Ω
Fall time	t _f	_	4.2		ns	Rg = 4.7 Ω
Body-drain diode forward voltage	V_{DF}	_	0.80	1.04	V	IF = 16 A, V_{GS} = 0 ^{Note4}
Body–drain diode reverse recovery time	t _{rr}	_	30	—	ns	IF = 16 A, V _{GS} = 0 diF/ dt = 100 A/ μs
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Notes: 4. Pulse test

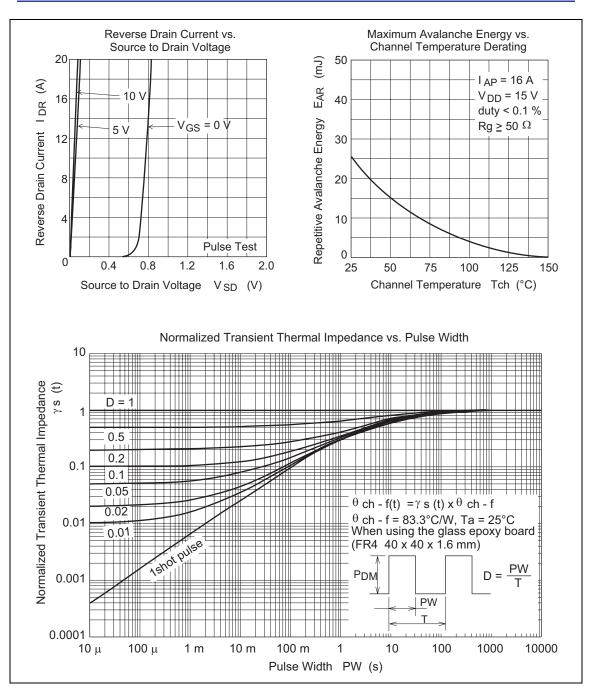




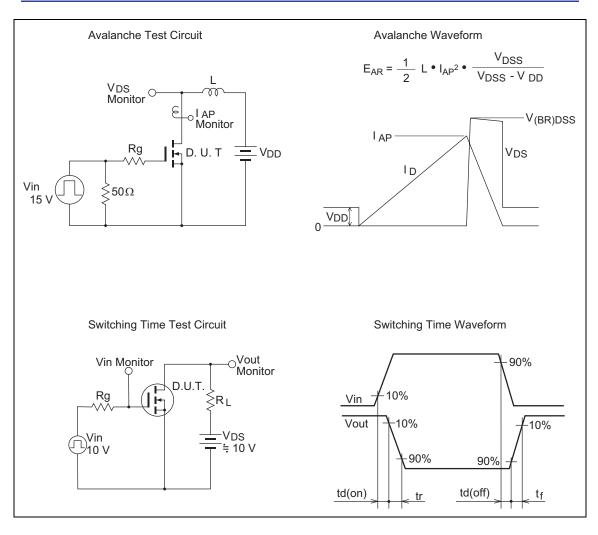
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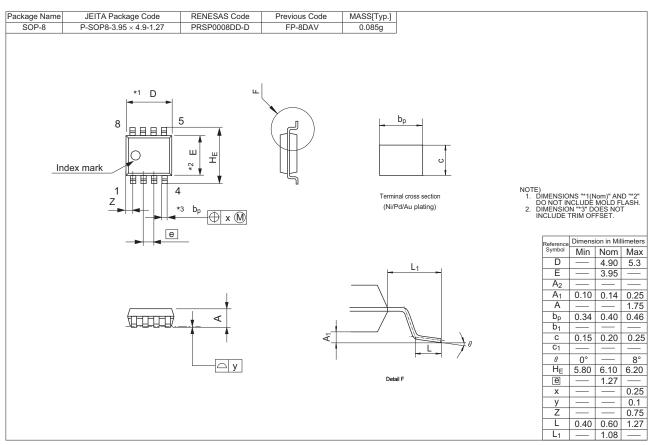
RENESAS



HAT2197R



Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
HAT2197R-EL-E	2500 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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